L	Hits	Search Text	DB	Time stamp
Number				
1	306	semiconductor and (complementary adj	USPAT;	2003/04/05
į		bipolar adj transistors)	US-PGPUB;	13:59
1			EPO; JPO;	
			DERWENT;	
			IBM TDB	
2 .	131	(semiconductor and (complementary adj	USPAT;	2003/04/05
		bipolar adj transistors)) and electrode	US-PGPUB;	14:00
			EPO; JPO;	
			DEPWENT;	
			IBM TDB	
3	120	((semiconductor and (complementary adj	USPAT;	2003/04/05
		bipolar adj transistors)) and	US-PGPUB;	14:00
		electrode) and emitter and base and	EPO; JPO;	
		collector	DEPWENT;	
			IBM TDB	•
4	74	(((semiconductor and (complementary adj	USPAT;	2003/04/05
		bipolar adj transistors)) and	US-PGPUB;	14:01
		electrode) and emitter and base and	EPO; JPO;	
,		collector) and ((polycrystal\$4 adj	DERWENT;	
		(silicon or si)) or polysilicon)	IBM TDB	i a

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L	Hits	Search Text	DB	Time stamp
Number				
1	1482	(438/207, 309, 313, 318, 213, 205, 322, 323, 203, "348").CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/05 15:02

A. 4.4